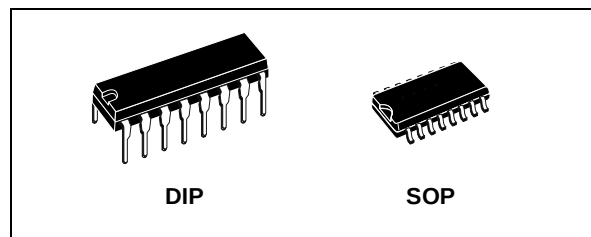


8-BIT PRIORITY ENCODER

- CONVERTS FROM 1 TO 8 TO INPUTS BINARY
- PROVIDES CASCADING FEATURE TO HANDLE ANY NUMBER OF INPUTS
- GROUP SELECT INDICATES ONE OR MORE PRIORITY INPUTS
- QUIESCENT CURRENT SPECIFIED UP TO 20V
- STANDARDIZED SYMMETRICAL OUTPUT CHARACTERISTICS
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT
 $I_l = 100\text{nA (MAX) AT } V_{DD} = 18\text{V } T_A = 25^\circ\text{C}$
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B "STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"

DESCRIPTION

HCF4532B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages. HCF4532B consists of a combinational logic that encodes the highest priority input (D7-D0) to a 3-bit binary code. The eight inputs, D7 through D0,



ORDER CODES

PACKAGE	TUBE	T & R
DIP	HCF4532BEY	
SOP	HCF4532BM1	HCF4532M013TR

each have an assigned priority. D7 is the highest priority and D0 is the lowest. The priority encoder is inhibited when the chip enable input E_1 is low. When E_1 is high, the binary representation of the highest priority input appears on output lines Q2-Q0, and the group select line GS is high to indicate that priority inputs are present. The enable out (E_O) is high when no priority inputs are present. If any input is high, E_O is low and all cascaded lower order stages are disabled.

PIN CONNECTION

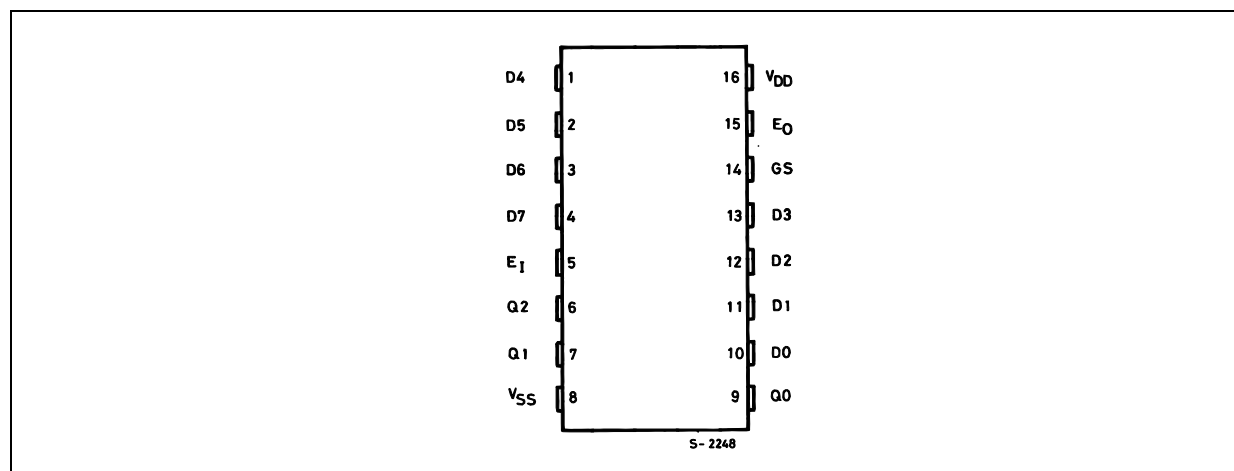


Figure 1: Input Equivalent Circuit

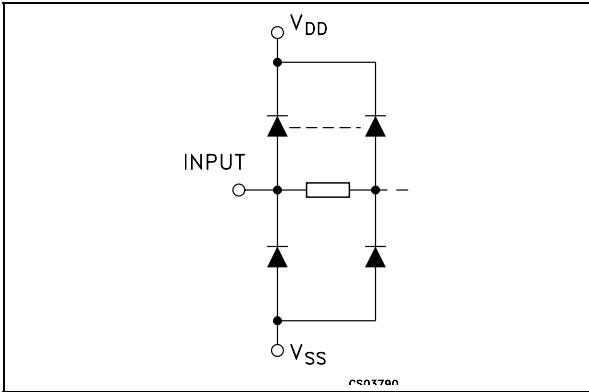


Table 1: Pin Description

PIN N°	SYMBOL	NAME AND FUNCTION
10, 11, 12, 13, 1, 2, 3, 4	D0 to D7	Data Inputs
9, 7, 6	Q0 to Q2	Data Output Lines
5	E _I	Chip Enable Input
15	E _O	Enable Output
14	GS	Group Select Line
8	V _{SS}	Negative Supply Voltage
16	V _{DD}	Positive Supply Voltage

Figure 2: Functional Diagram

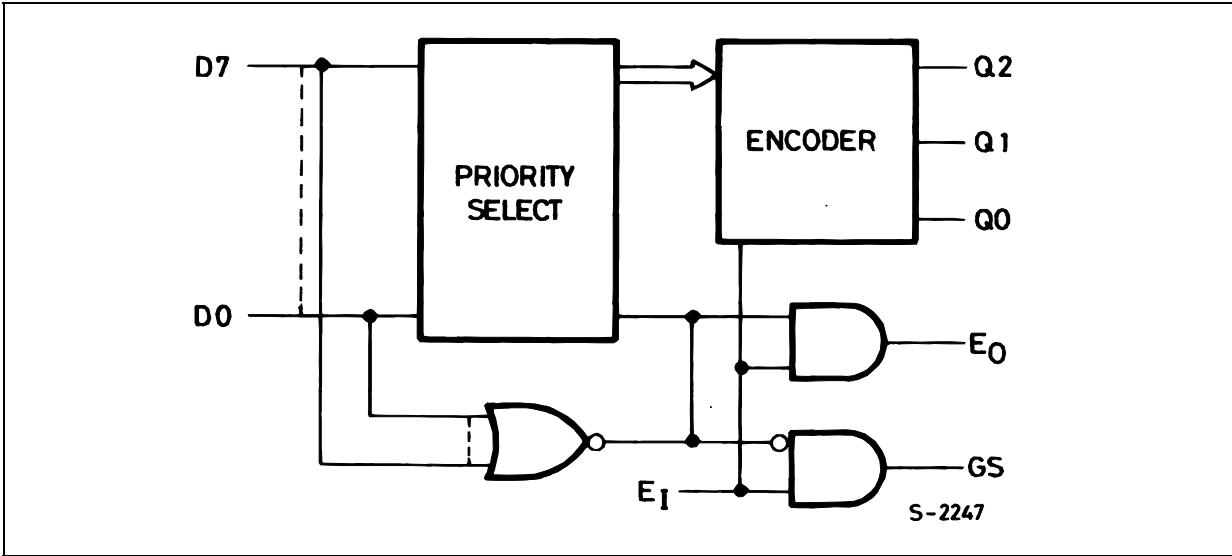


Table 2: Truth Table

INPUTS									OUTPUTS				
E _I	D7	D6	D5	D4	D3	D2	D1	D0	GS	Q2	Q1	Q0	E _O
L	X	X	X	X	X	X	X	X	L	L	L	L	L
H	L	L	L	L	L	L	L	L	L	L	L	L	H
H	H	X	X	X	X	X	X	X	H	H	H	H	L
H	L	H	X	X	X	X	X	X	H	H	H	L	L
H	L	L	H	X	X	X	X	X	H	H	L	H	L
H	L	L	L	H	X	X	X	X	H	H	L	L	L
H	L	L	L	L	H	X	X	X	H	L	H	H	L
H	L	L	L	L	L	H	X	X	H	L	H	L	L
H	L	L	L	L	L	L	H	X	H	L	L	H	L
H	L	L	L	L	L	L	L	H	H	L	L	L	L

X : Don't Care

Figure 3: Logic Diagram

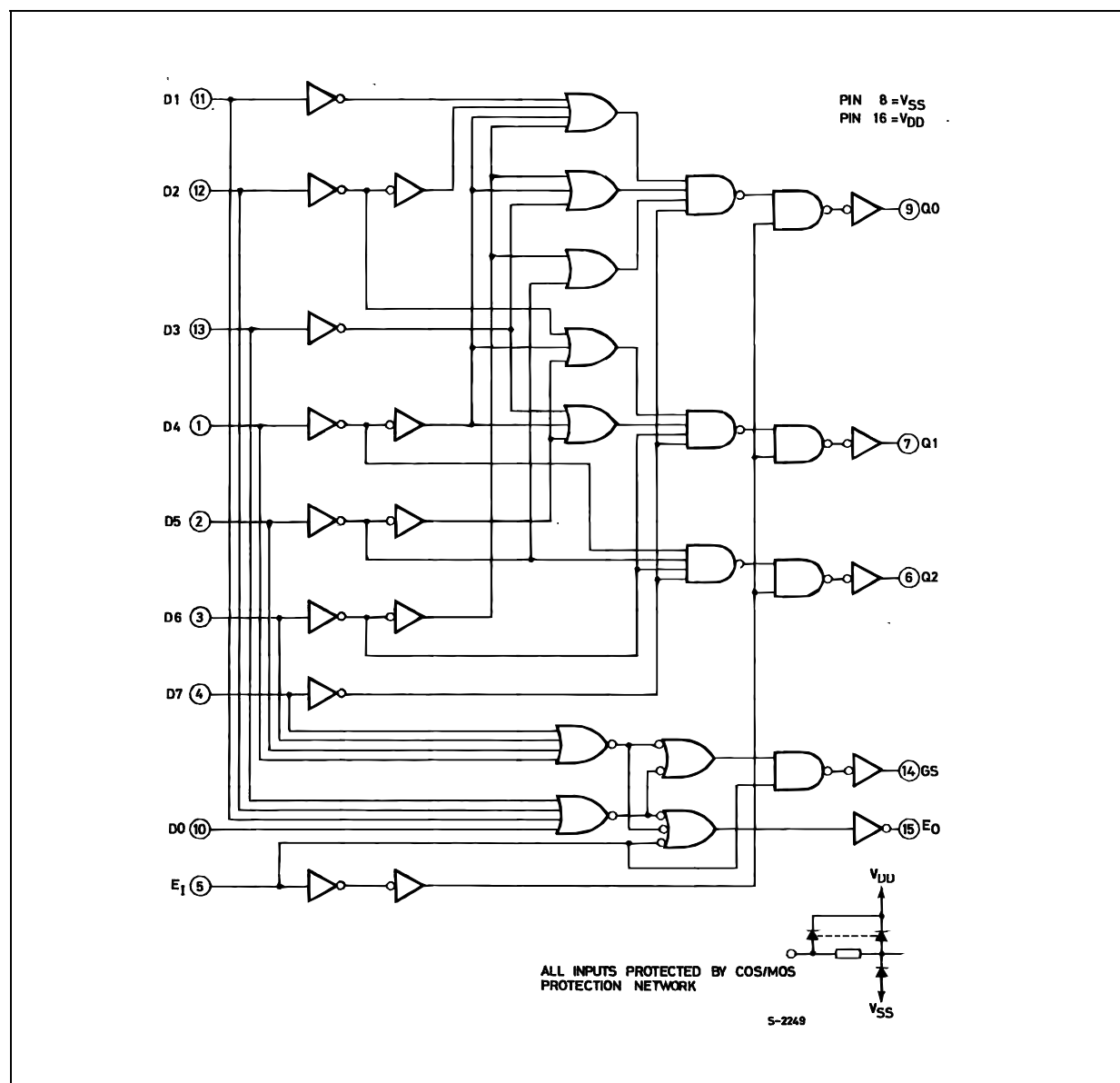


Table 3: Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	-0.5 to +22	V
V_I	DC Input Voltage	-0.5 to $V_{DD} + 0.5$	V
I_I	DC Input Current	± 10	mA
P_D	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T_{op}	Operating Temperature	-55 to +125	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-65 to +150	$^{\circ}\text{C}$

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V_{SS} pin voltage.

Table 4: Recommended Operating Conditions

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	3 to 20	V
V_I	Input Voltage	0 to V_{DD}	V
T_{op}	Operating Temperature	-55 to 125	°C

Table 5: DC Specifications

Symbol	Parameter	Test Condition				Value								Unit
		V _I (V)	V _O (V)	I _{OL} (μA)	V _{DD} (V)	T _A = 25°C			-40 to 85°C		-55 to 125°C			
						Min.	Typ.	Max.	Min.	Max.	Min.	Max.		
I _L	Quiescent Current	0/5			5		0.04	5		150		150	μA	
		0/10			10		0.04	10		300		300		
		0/15			15		0.04	20		600		600		
		0/20			20		0.08	100		3000		3000		
V _{OH}	High Level Output Voltage	0/5		<1	5	4.95			4.95		4.95		V	
		0/10		<1	10	9.95			9.95		9.95			
		0/15		<1	15	14.95			14.95		14.95			
V _{OL}	Low Level Output Voltage	5/0		<1	5		0.05			0.05		0.05	V	
		10/0		<1	10		0.05			0.05		0.05		
		15/0		<1	15		0.05			0.05		0.05		
V _{IH}	High Level Input Voltage		0.5/4.5	<1	5	3.5			3.5		3.5		V	
			1/9	<1	10	7			7		7			
			1.5/13.5	<1	15	11			11		11			
V _{IL}	Low Level Input Voltage		4.5/0.5	<1	5			1.5		1.5		1.5	V	
			9/1	<1	10			3		3		3		
			13.5/1.5	<1	15			4		4		4		
I _{OH}	Output Drive Current	0/5	2.5	<1	5	-1.36	-3.2		-1.1		-1.1		mA	
		0/5	4.6	<1	5	-0.44	-1		-0.36		-0.36			
		0/10	9.5	<1	10	-1.1	-2.6		-0.9		-0.9			
		0/15	13.5	<1	15	-3.0	-6.8		-2.4		-2.4			
I _{OL}	Output Sink Current	0/5	0.4	<1	5	0.44	1		0.36		0.36		mA	
		0/10	0.5	<1	10	1.1	2.6		0.9		0.9			
		0/15	1.5	<1	15	3.0	6.8		2.4		2.4			
I _I	Input Leakage Current	0/18	Any Input		18		±10 ⁻⁵	±0.1		±1		±1	μA	
C _I	Input Capacitance		Any Input				5	7.5					pF	

The Noise Margin for both "1" and "0" level is: 1V min. with $V_{DD}=5V$, 2V min. with $V_{DD}=10V$, 2.5V min. with $V_{DD}=15V$

Table 6: Dynamic Electrical Characteristics ($T_{amb} = 25^{\circ}\text{C}$, $C_L = 50\text{pF}$, $R_L = 200\text{K}\Omega$, $t_r = t_f = 20\text{ ns}$)

Symbol	Parameter	Test Condition		Value (*)			Unit
		V_{DD} (V)		Min.	Typ.	Max.	
t_{PLH} t_{PHL}	Propagation Delay Time (E_I to E_O , E_I to GS)	5			110	220	ns
		10			55	110	
		15			45	85	
t_{PLH} t_{PHL}	Propagation Delay Time (E_I to Q_m , D_n to GS)	5			170	340	ns
		10			85	170	
		15			65	125	
t_{PLH} t_{PHL}	Propagation Delay Time (D_n to Q_m)	5			220	440	ns
		10			110	220	
		15			85	160	
t_{TLH} t_{THL}	Transition Time	5			100	200	ns
		10			50	100	
		15			40	80	

(*) Typical temperature coefficient for all V_{DD} value is 0.3 %/ $^{\circ}\text{C}$.

TYPICAL APPLICATIONS

Figure 4: 16-Level Priority Encoder

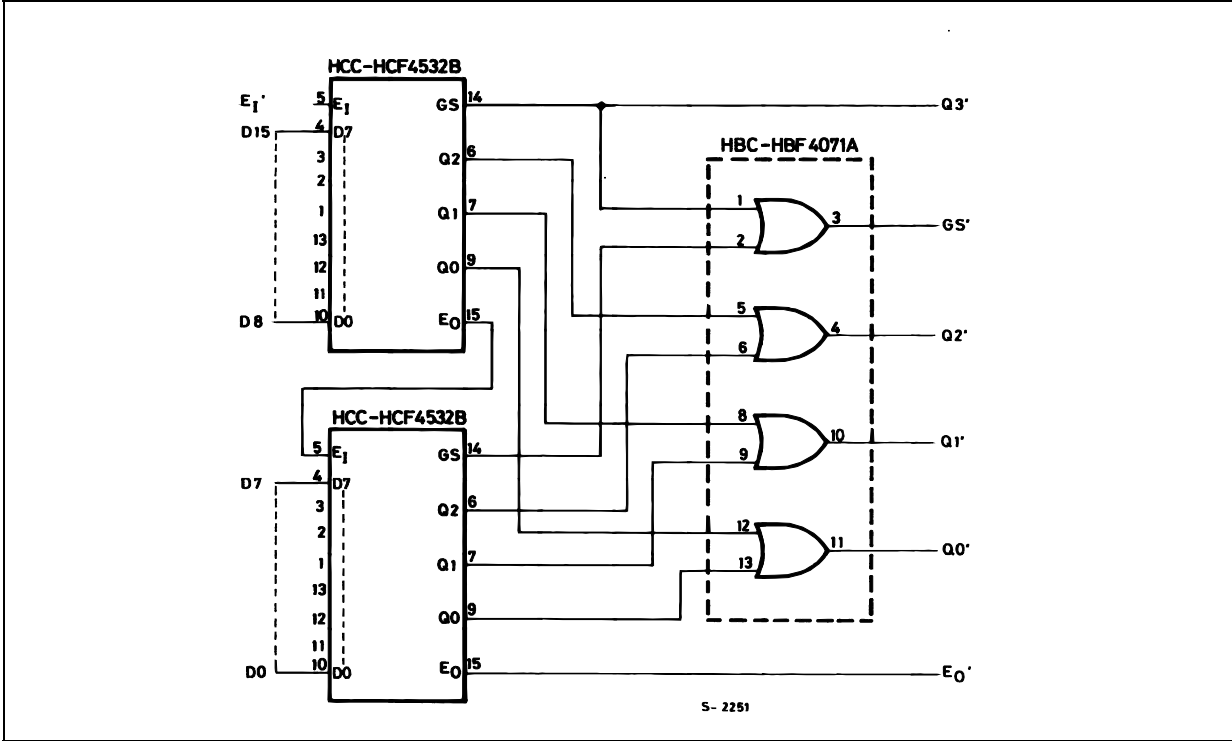


Figure 6: Digital To Analog Conversion

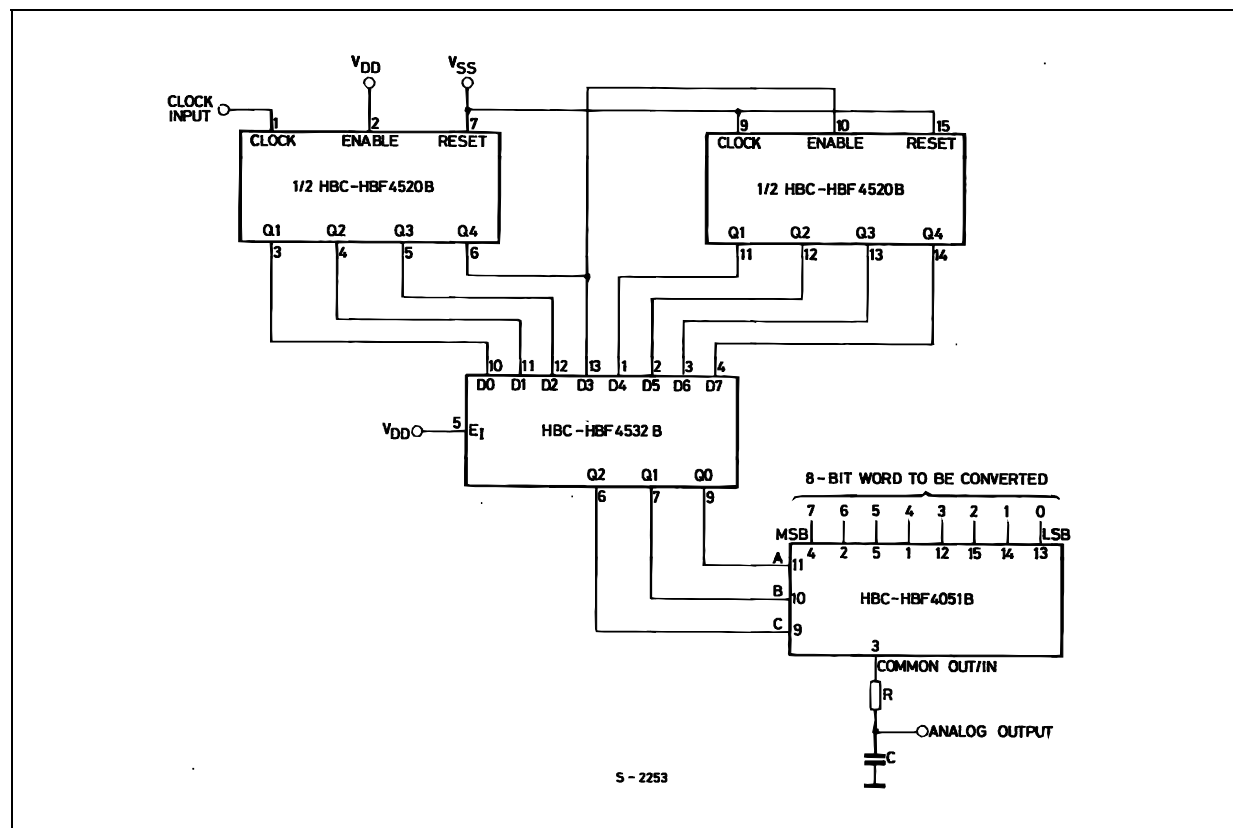
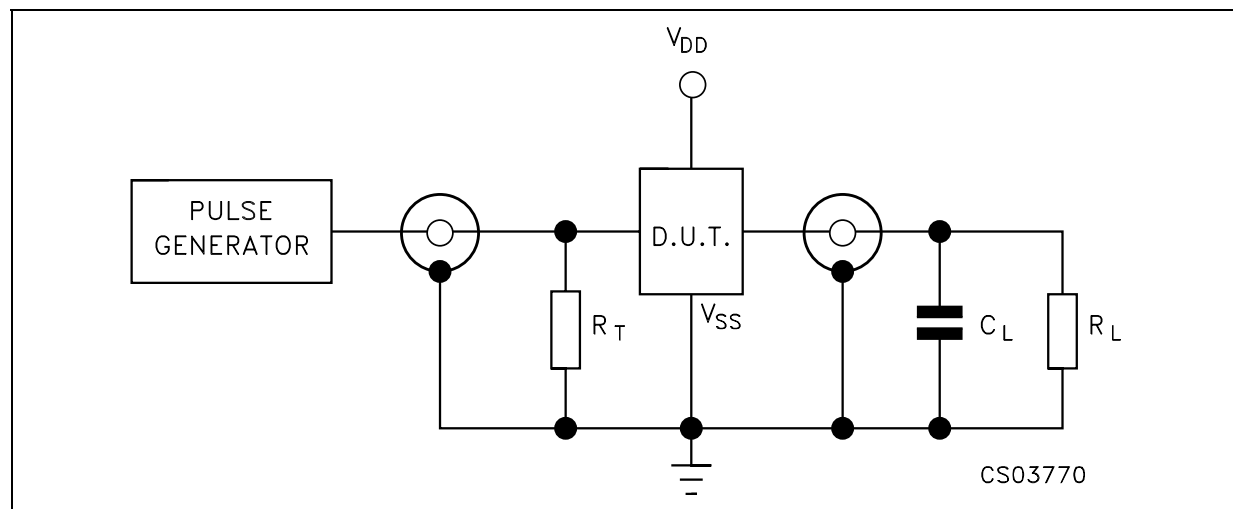


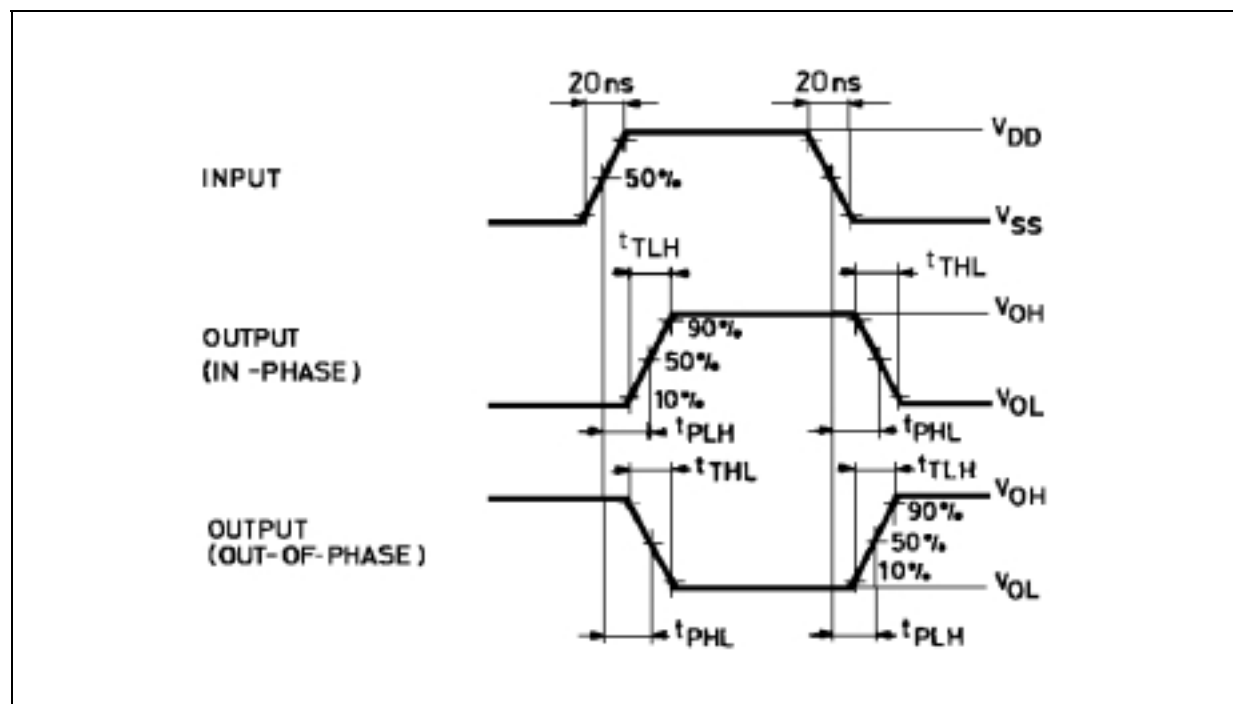
Figure 7: Test Circuit



C_L = 50pF or equivalent (includes jig and probe capacitance)

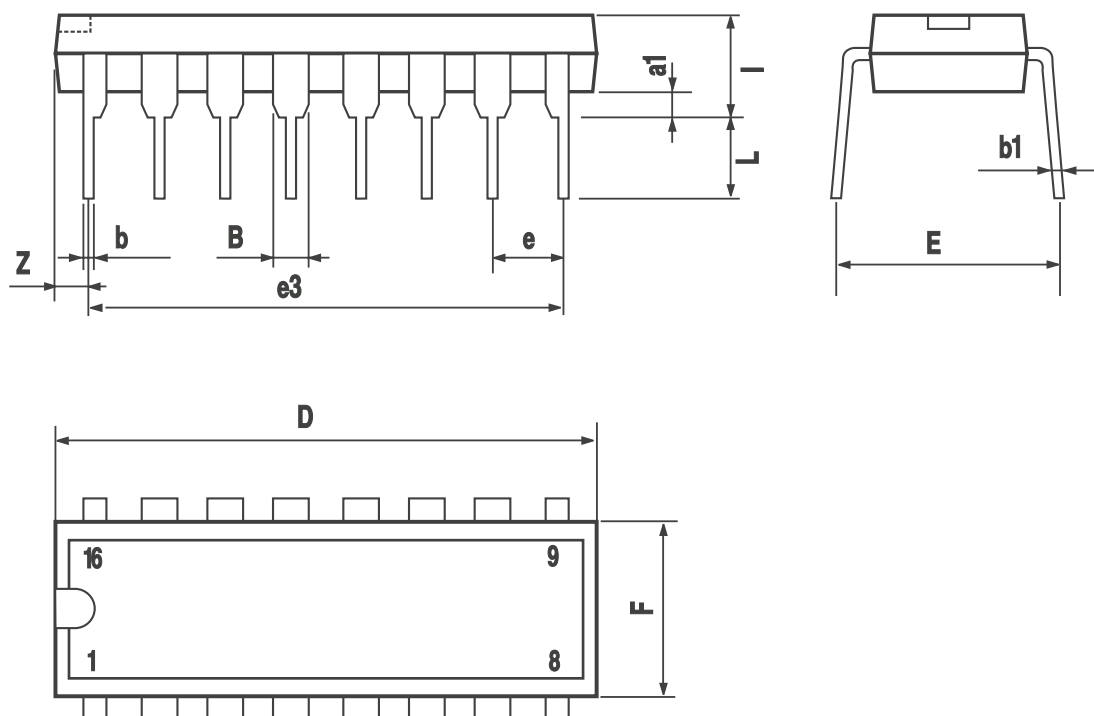
R_L = 200K Ω

R_T = Z_{OUT} of pulse generator (typically 50 Ω)

Figure 8: Waveform - Propagation Delay Times ($f=1\text{MHz}$; 50% duty cycle)

Plastic DIP-16 (0.25) MECHANICAL DATA

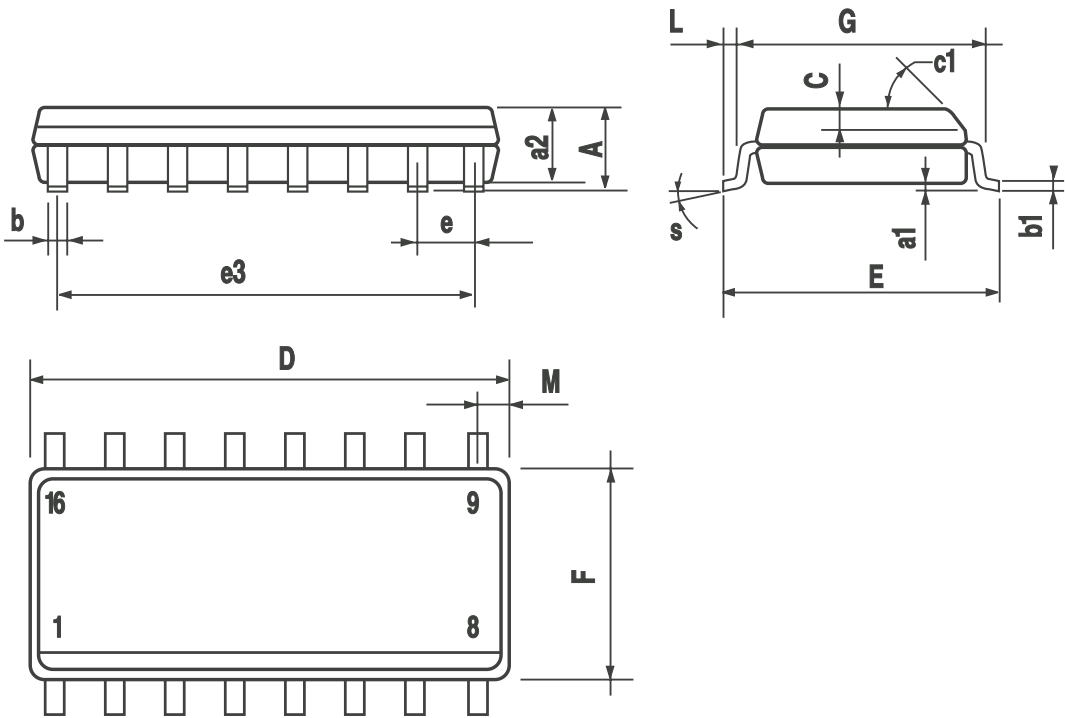
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050



P001C

SO-16 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.004		0.008
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8° (max.)					



PO13H

Tape & Reel SO-16 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			22.4			0.882
Ao	6.45		6.65	0.254		0.262
Bo	10.3		10.5	0.406		0.414
Ko	2.1		2.3	0.082		0.090
Po	3.9		4.1	0.153		0.161
P	7.9		8.1	0.311		0.319

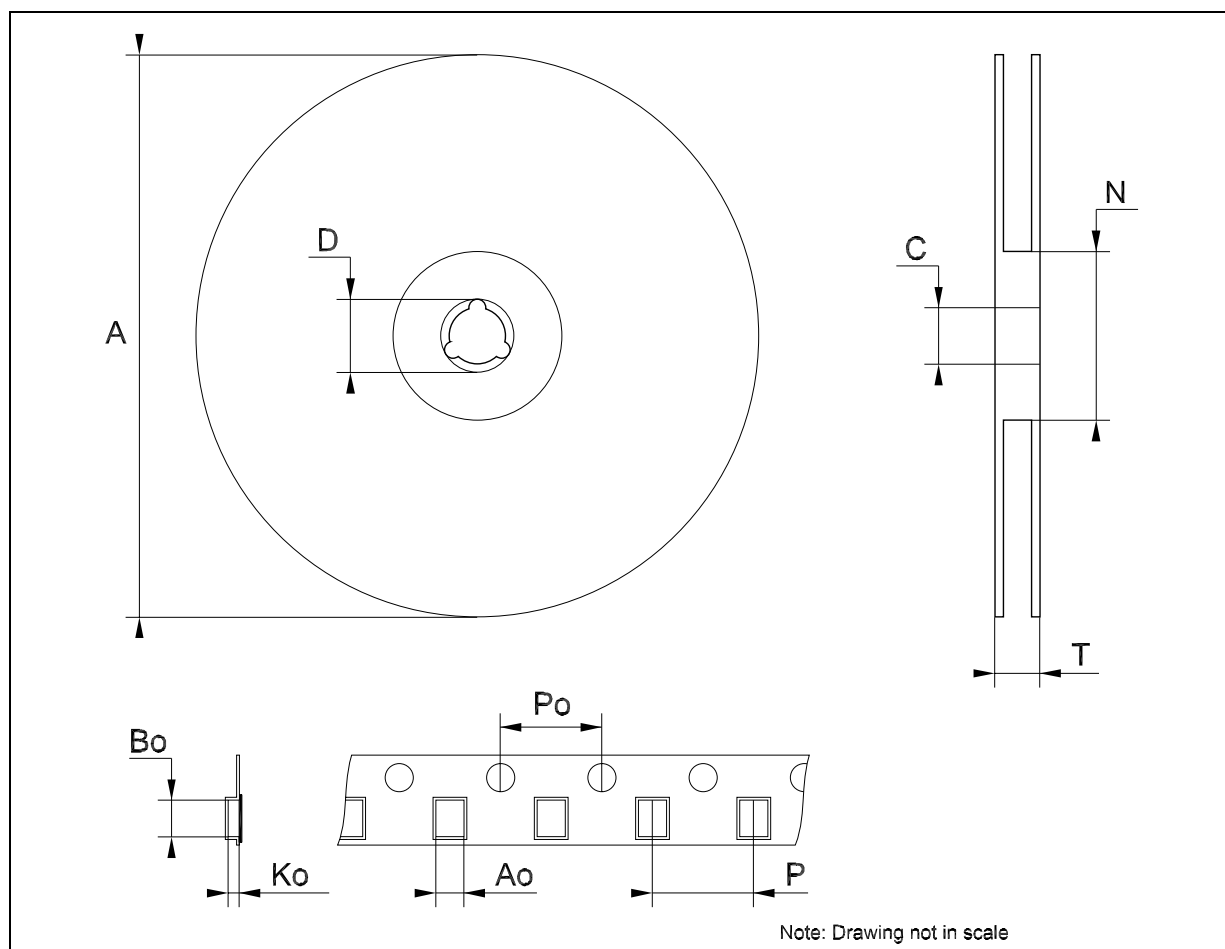


Table 8: Revision History

Date	Revision	Description of Changes
07-May-2004	2	Mistake Truth Table - Table 2 - Pag. 2

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